


DXT2013P5
100V PNP MEDIUM POWER TRANSISTOR
PowerDI®5
Features

- 43% smaller than SOT223; 60% smaller than TO252
- Maximum height just 1.1mm
- Rated up to 3.2W
- $V_{CEO} = -100V$
- $I_C = -5A$; $I_{CM} = -10A$
- Low Saturation voltage
- **Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**

Applications

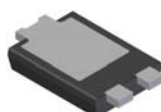
- SLIC DC-DC Converter

Mechanical Data

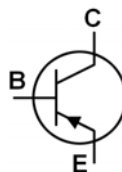
- Case: PowerDI®5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 Ⓔ3
- Weight: 0.093 grams (approximate)



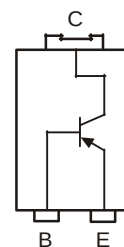
Top View



Bottom View



Device Schematic

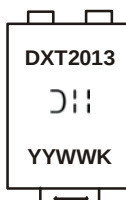


Pin-out diagram

Ordering Information (Note 3)

Part Number	Case	Packaging
DXT2013P5-13	PowerDI®5	5000/Tape & Reel

- Notes:
1. No purposefully added lead. Halogen and Antimony Free.
 2. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>
 3. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information


DXT2013 = Product Type Marking Code
 = Manufacturers' Code Marking
 K = Factory Designator
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 09 for 2009)
 WW = Week code (01 to 53)

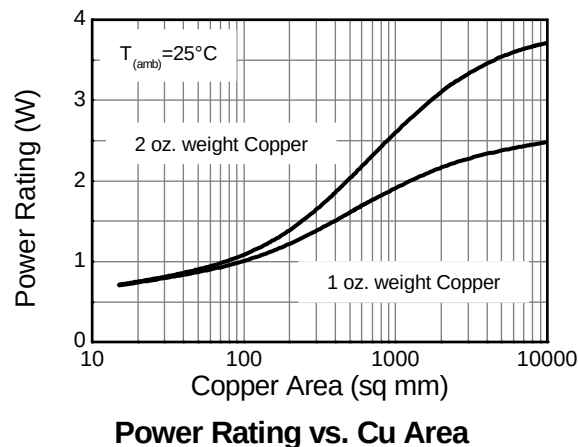
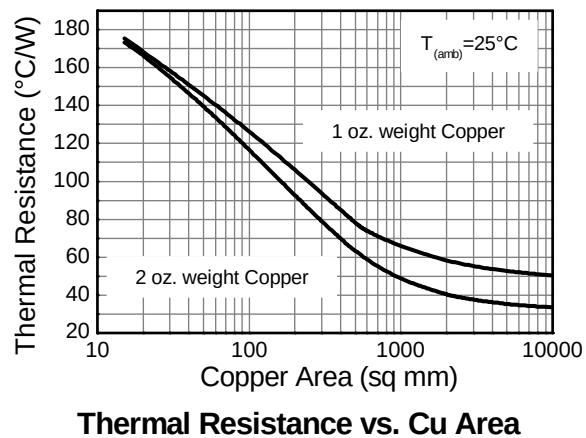
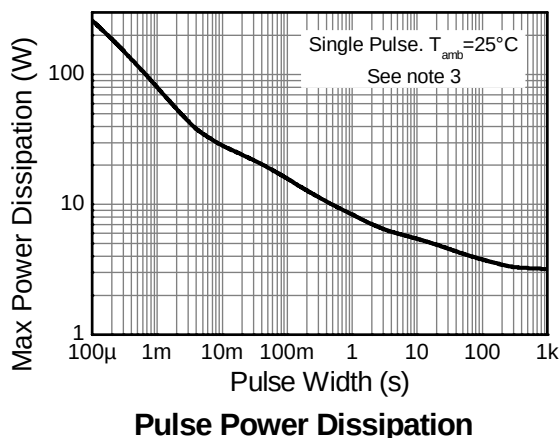
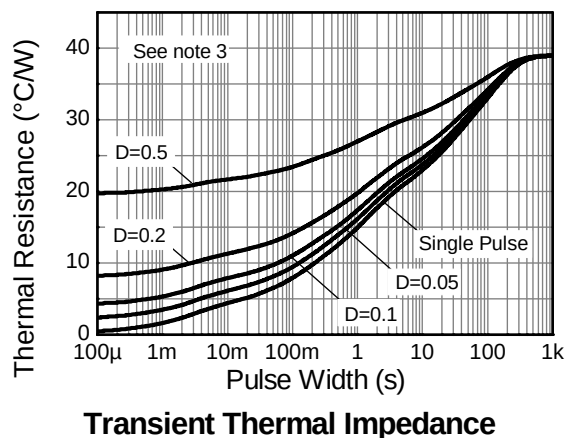
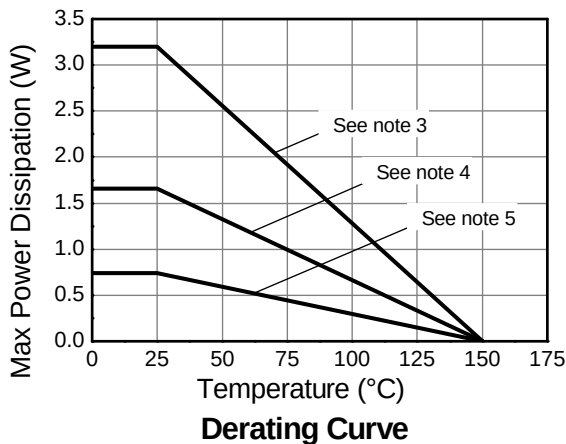
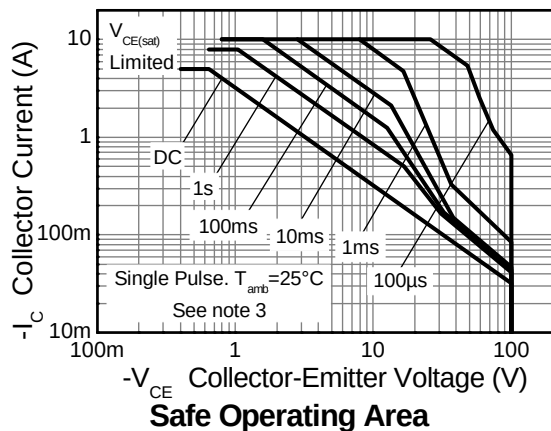
Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-140	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-5	A
Peak Pulse Current	I _{CM}	-10	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ T _A = 25°C (Note 4)	P _D	3.2	W
Thermal Resistance, Junction to Ambient Air (Note 4) @T _A = 25°C	R _{θJA}	39	°C/W
Power Dissipation @ T _A = 25°C (Note 5)	P _D	1.7	W
Thermal Resistance, Junction to Ambient Air (Note 5) @T _A = 25°C	R _{θJA}	75	°C/W
Power Dissipation @ T _A = 25°C (Note 6)	P _D	0.74	W
Thermal Resistance, Junction to Ambient Air (Note 6) @T _A = 25°C	R _{θJA}	169	°C/W
Thermal Resistance, Junction to Collector Terminal	R _{θJT}	5.6	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Notes:
4. Device mounted on FR-4 PCB, single sided 2 oz. copper, collector pad dimensions 50mm x 50mm.
 5. Device mounted on FR-4 PCB, single sided 1 oz. copper, collector pad dimensions 25mm x 25mm.
 6. Device mounted on FR-4 PCB, single sided 1 oz. copper, minimum recommended pad layout.

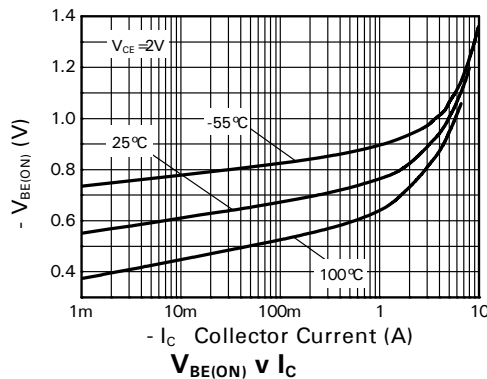
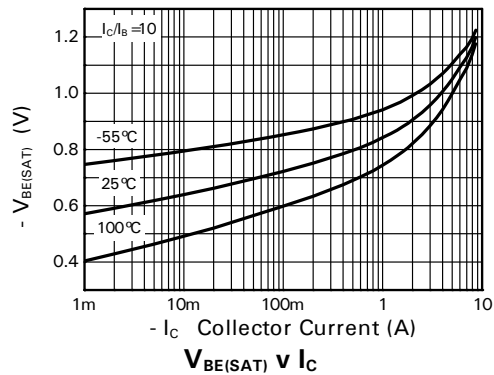
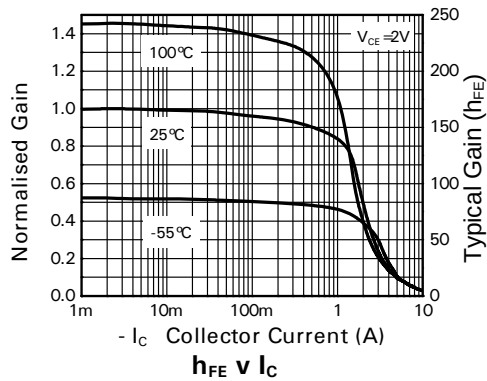
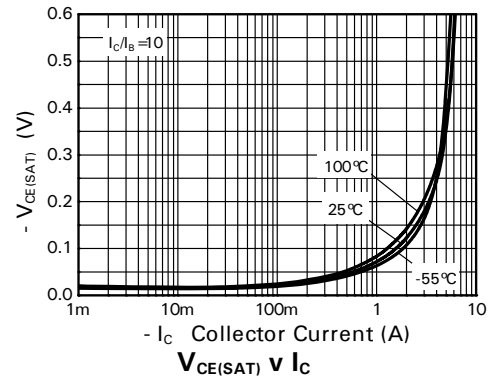
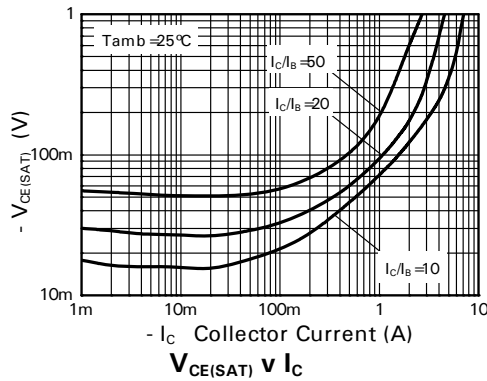


Electrical Characteristics @T_A = 25°C unless otherwise specified

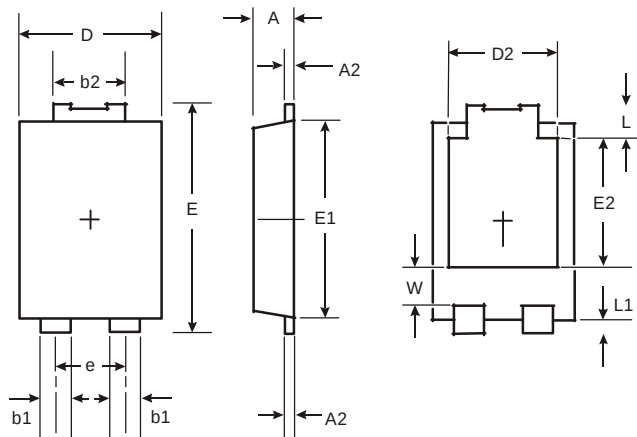
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-140	-160	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 7)	V _{(BR)CEO}	-100	-115	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-7.0	-8.1	—	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	—	<1	-20 -0.5	nA μA	V _{CB} = -100V V _{CB} = -100V, T _{amb} = 100 °C
Collector Cutoff Current	I _{CER} R ≤ 1kΩ	—	<1	-20 -0.5	nA μA	V _{CB} = -100V V _{CB} = -100V, T _{amb} = 100 °C
Emitter Cutoff Current	I _{EBO}	—	<1	-10	nA	V _{EB} = -6V
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	—	-20 -70 -120 -240	-30 -90 -150 -340	mV	I _C = -0.1A, I _B = -10mA I _C = -1A, I _B = -100mA I _C = -2A, I _B = -200mA I _C = -4A, I _B = -400mA
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	—	-985	-1100	mV	I _C = -4A, I _B = -400mA
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(on)}	—	-920	-1050	mV	V _{CE} = -4V, I _C = -2A
DC Current Gain (Note 7)	h _{FE}	100 100 25 15 —	250 200 50 30 5	— 300 — — —	—	I _C = -10mA, V _{CE} = -1V I _C = -1A, V _{CE} = -1V I _C = -3A, V _{CE} = -1V I _C = -4A, V _{CE} = -1V I _C = -10A, V _{CE} = -1V
Transition Frequency	f _T	—	125	—	MHz	I _C = -100mA, V _{CE} = -10V, f = 50MHz
Output Capacitance	C _{obo}	—	42	—	pF	V _{CB} = -10V, f = 1MHz
Switching Times	t _{on} t _{off}	— —	42 540	— —	ns ns	I _C = -1A, V _{CC} = -10V, I _{B1} = I _{B2} = -100mA

Notes: 7. Pulse Test: Pulse width ≤ 300μs. Duty cycle ≤ 2.0%.

Typical Characteristic

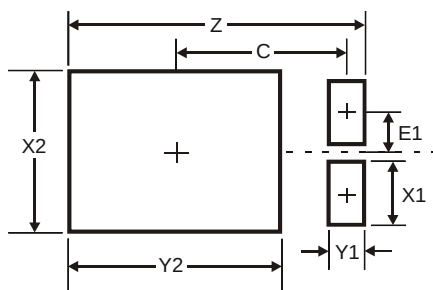


Package Outline Dimensions



PowerDI [®] 5		
Dim	Min	Max
A	1.05	1.15
A2	0.33	0.43
b1	0.80	0.99
b2	1.70	1.88
D	3.90	4.05
D2	3.054 Typ	
E	6.40	6.60
e	1.84 Typ	
E1	5.30	5.45
E2	3.549 Typ	
L	0.75	0.95
L1	0.50	0.65
W	1.10	1.41
All Dimensions in mm		

Suggested Pad Layout



Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
C	3.87
E1	0.9

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

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moschip.ru_9